MOSFETs Silicon N-Channel MOS (π-MOSVII)

TK12A65D

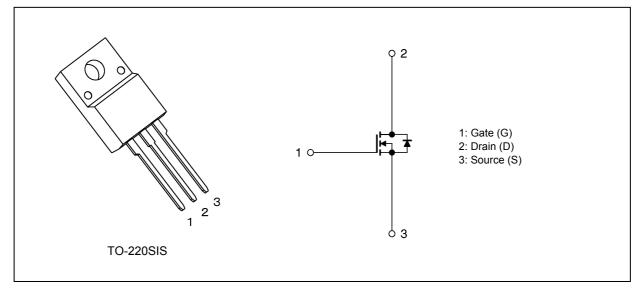
1. Applications

• Switching Voltage Regulators

2. Features

- (1) Low drain-source on-resistance: $R_{DS(ON)} = 0.46 \Omega$ (typ.)
- (2) High forward transfer admittance: $|Y_{fs}| = 6.0 \text{ S}$ (typ.)
- (3) Low leakage current: $I_{DSS} = 10 \ \mu A \ (max) \ (V_{DS} = 650 \ V)$
- (4) Enhancement mode: V_{th} = 2.0 to 4.0 V (V_{DS} = 10 V, I_D = 1 mA)

3. Packaging and Internal Circuit



4. Absolute Maximum Ratings (Note) ($T_a = 25^{\circ}C$ unless otherwise specified)

| Characteristics | Symbol | Rating | Unit | |
|---|----------|------------------|------------|----|
| Drain-source voltage | | V _{DSS} | 650 | V |
| Gate-source voltage | | V _{GSS} | ±30 | |
| Drain current (DC) | (Note 1) | Ι _D | 12 | Α |
| Drain current (pulsed) | (Note 1) | I _{DP} | 48 | 1 |
| Power dissipation $(T_c = 25^{\circ}C)$ | | PD | 50 | W |
| Single-pulse avalanche energy | (Note 2) | E _{AS} | 611 | mJ |
| Avalanche current | | I _{AR} | 12 | A |
| Repetitive avalanche energy | (Note 3) | E _{AR} | 5.0 | mJ |
| Channel temperature | | T _{ch} | 150 | °C |
| Storage temperature | | T _{stg} | -55 to 150 | |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Start of commercial production 2010-09 2013-12-25 Rev.2.0

5. Thermal Characteristics

| Characteristics | Symbol | Max | Unit |
|---------------------------------------|-----------------------|------|------|
| Channel-to-case thermal resistance | R _{th(ch-c)} | 2.5 | °C/W |
| Channel-to-ambient thermal resistance | R _{th(ch-a)} | 62.5 | |

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: V_{DD} = 90 V, T_{ch} = 25°C (initial), L = 7.5 mH, R_G = 25 Ω , I_{AR} = 12 A

Note 3: Repetitive rating; pulse width limited by maximum channel temperature

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

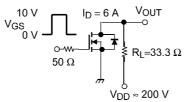
6. Electrical Characteristics

6.1. Static Characteristics (Ta = 25°C unless otherwise specified)

| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|--------------------------------|----------------------|--|-----|------|------|------|
| Gate leakage current | I _{GSS} | V_{GS} = ±30 V, V_{DS} = 0 V | _ | _ | ±1 | μA |
| Drain cut-off current | I _{DSS} | V _{DS} = 650 V, V _{GS} = 0 V | _ | _ | 10 | |
| Drain-source breakdown voltage | V _{(BR)DSS} | I _D = 10 mA, V _{GS} = 0 V | 650 | — | — | V |
| Gate threshold voltage | V _{th} | V _{DS} = 10 V, I _D = 1 mA | 2.0 | _ | 4.0 | |
| Drain-source on-resistance | R _{DS(ON)} | V _{GS} = 10 V, I _D = 6 A | _ | 0.46 | 0.54 | Ω |
| Forward transfer admittance | Y _{fs} | V _{DS} = 10 V, I _D = 6 A | 1.7 | 6.0 | | S |

6.2. Dynamic Characteristics ($T_a = 25^{\circ}C$ unless otherwise specified)

| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|--------------------------------|------------------|--|-----|------|-----|------|
| Input capacitance | C _{iss} | V _{DS} = 25 V, V _{GS} = 0 V, f = 1 MHz | | 2300 | — | pF |
| Reverse transfer capacitance | C _{rss} | | _ | 10 | — | |
| Output capacitance | C _{oss} | | | 200 | _ | |
| Switching time (rise time) | t _r | See Figure 6.2.1. | | 35 | — | ns |
| Switching time (turn-on time) | t _{on} | | _ | 90 | — | |
| Switching time (fall time) | t _f | | | 20 | — | |
| Switching time (turn-off time) | t _{off} | | _ | 150 | _ | |



Duty \leq 1%, t_W = 10 μ s



6.3. Gate Charge Characteristics ($T_a = 25^{\circ}C$ unless otherwise specified)

| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|---|-----------------|--|-----|------|-----|------|
| Total gate charge (gate-source plus gate-drain) | Qg | $V_{DD} \approx 400 \text{ V}, V_{GS} \text{ = } 10 \text{V}, \text{I}_{D} \text{ = } 12 \text{A}$ | — | 40 | — | nC |
| Gate-source charge | Q _{gs} | | _ | 28 | _ | |
| Gate-drain charge | Q _{gd} | | _ | 12 | _ | |

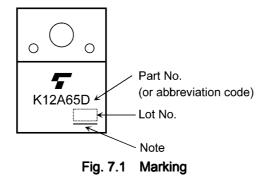
6.4. Source-Drain Characteristics ($T_a = 25^{\circ}C$ unless otherwise specified)

| Characteristics | | Symbol | Test Condition | Min | Тур. | Max | Unit |
|--------------------------------|----------|------------------|--|-----|------|------|------|
| Reverse drain current (DC) | (Note 1) | I _{DR} | — | - | _ | 12 | A |
| Reverse drain current (pulsed) | (Note 1) | I _{DRP} | — | | | 48 | |
| Diode forward voltage | | V _{DSF} | I _{DR1} = 12 A, V _{GS} = 0 V | | | -1.7 | V |
| Reverse recovery time | | t _{rr} | I _{DR} = 12 A, V _{GS} = 0 V | _ | 1400 | _ | ns |
| Reverse recovery charge | | Q _{rr} | -dI _{DR} /dt = 100 A/μs | | 16 | _ | μC |

TK12A65D

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7. Marking (Note)



 Note:
 A line under a Lot No. identifies the indication of product Labels.

 Not underlined: [[Pb]]/INCLUDES > MCV

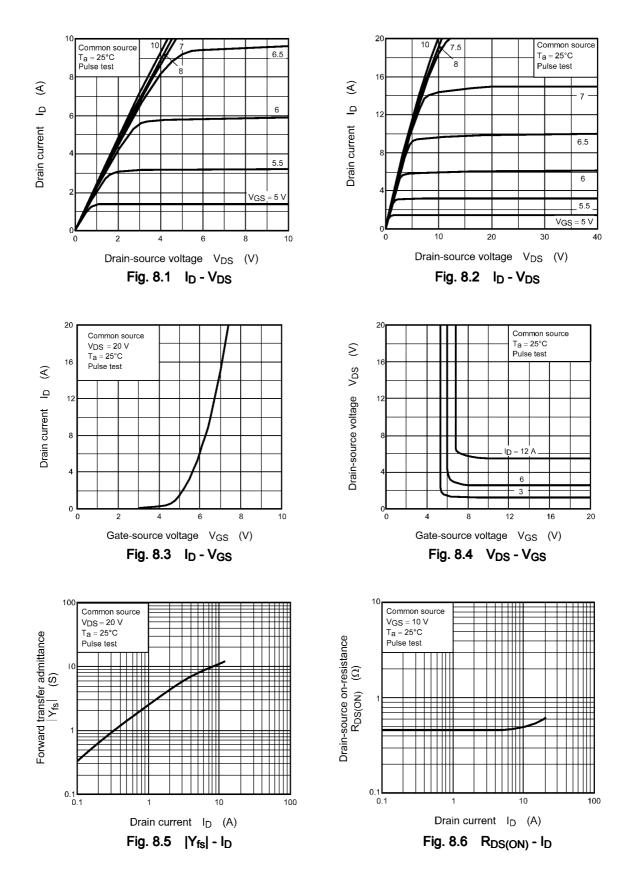
 Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

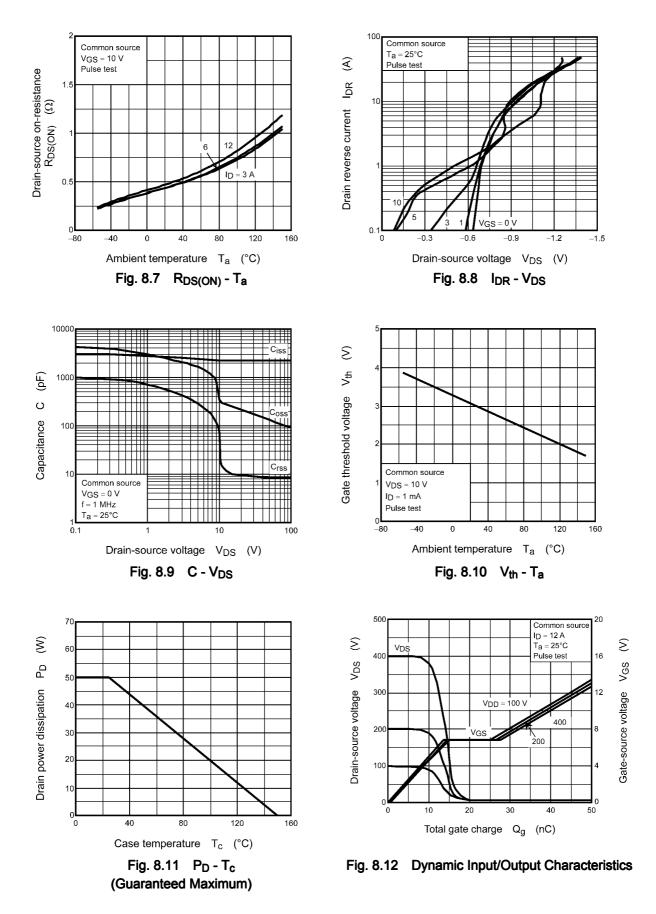
 Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.

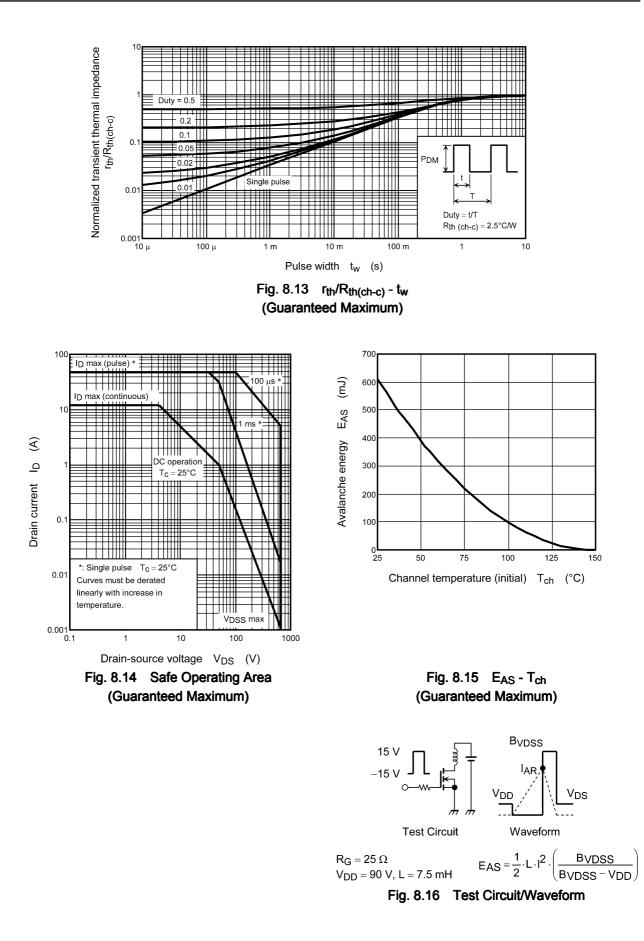
 The RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the

The RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

8. Characteristics Curves (Note)





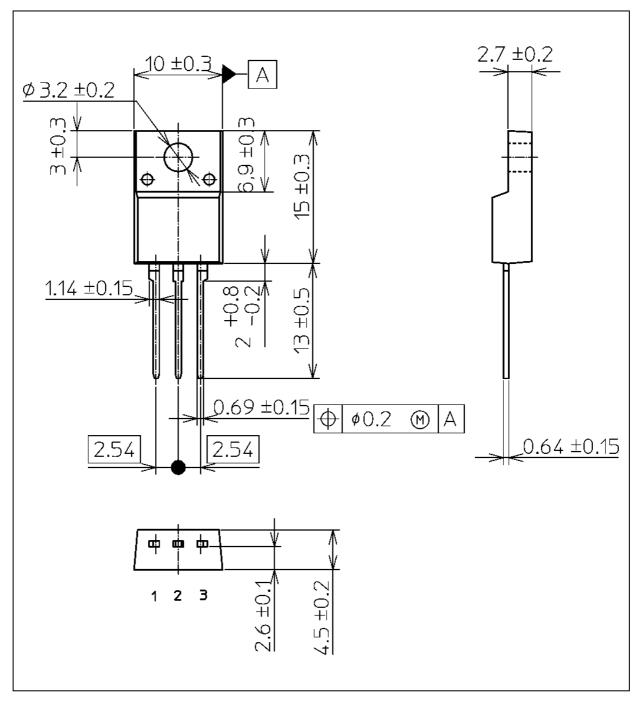


Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

Package Dimensions

TK12A65D

Unit: mm



Weight: 1.7 g (typ.)

| Pac | ckage Name(s) |
|---------------------|---------------|
| JEITA: SC-67 | |
| TOSHIBA: 2-10U1S | |
| Nickname: TO-220SIS | |

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